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PSMN0R7-25YLD

N-channel 25 V, 0.72 m Ω , 300 A logic level MOSFET in LFPAK56 using NextPowerS3 Technology

21 April 2016

Product data sheet

1. General description

Logic level gate drive N-channel enhancement mode MOSFET in LFPAK56 package. NextPowerS3 portfolio utilising Nexperia's unique "SchottkyPlus" technology delivers high efficiency, low spiking performance usually associated with MOSFETS with an integrated Schottky or Schottky-like diode but without problematic high leakage current. NextPowerS3 is particularly suited to high efficiency applications at high switching frequencies.

2. Features and benefits

- 100% Avalanche tested at I_(AS) = 190 A
- Ultra low Q_G, Q_{GD} and Q_{OSS} for high system efficiency, especially at higher switching frequencies
- · Superfast switching with soft-recovery
- Low spiking and ringing for low EMI designs
- Unique "SchottkyPlus" technology; Schottky-like performance with < 1 μ A leakage at 25 °C
- Optimised for 4.5 V gate drive
- Low parasitic inductance and resistance
- High reliability clip bonded and solder die attach Power SO8 package; no glue, no wire bonds, qualified to 150 °C
- Wave solderable; exposed leads for optimal visual solder inspection

3. Applications

- On-board DC:DC solutions for server and telecommunications
- Secondary-side synchronous rectification in telecommunication applications
- Voltage regulator modules (VRM)
- Point-of-Load (POL) modules
- Power delivery for V-core, ASIC, DDR, GPU, VGA and system components
- Brushed and brushless motor control
- Power OR-ing

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 150 °C		-	-	25	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	300	Α



Symbol	Parameter	Conditions	M	in	Тур	Max	Unit
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-		-	158	W
Tj	junction temperature		-5	55	-	150	°C
Static chara	acteristics						
R _{DSon}	drain-source on-state resistance	V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C; Fig. 10	-		0.76	0.92	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10	-		0.57	0.72	mΩ
Dynamic ch	naracteristics					•	
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 10 V; Fig. 12; Fig. 13	-		110.2	-	nC
		I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13	-		50.9	-	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V	-		45.8	-	nC
Q_{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13	-		11.9	-	nC
Source-dra	in diode						,
S	softness factor	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$ $V_{DS} = 12 \text{ V}; Fig. 16$	-		0.9	-	

^{[1] 300}A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, Thermal design and operating temperature

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		D I
2	S	source		
3	S	source		G—U: A
4	G	Gate		mbb076 S
mb	D	mounting base; connected to drain	1 2 3 4	
			LFPAK56; Power- SO8 (SOT1023)	

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PSMN0R7-25YLD	LFPAK56; Power-SO8	Plastic single-ended surface-mounted package (LFPAK56); 4 leads	SOT1023		

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN0R7-25YLD	0D725L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 150 °C		-	25	V
V_{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 150 °C; R_{GS} = 20 kΩ		-	25	V
V_{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	158	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	300	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>	[1]	-	235	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 \text{ °C}$; Fig. 3		-	1482	Α
T _{stg}	storage temperature			-55	150	°C
Tj	junction temperature			-55	150	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
V _{ESD}	electrostatic discharge voltage	НВМ		2	-	kV
Source-dra	in diode					
I _S	source current	T _{mb} = 25 °C		-	132	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	1482	Α
Avalanche	ruggedness	1				
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	I_D = 300 A; V_{sup} ≤ 25 V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 36 μs		-	174	mJ

Symbol	Parameter	Conditions		Min	Max	Unit
I _{AS}	non-repetitive avalanche current	$V_{sup} \le 25 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C};$ $R_{GS} = 50 \Omega$	[2]	-	190	А

- [1] 300A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, Thermal design and operating temperature
- [2] Protected by 100% test

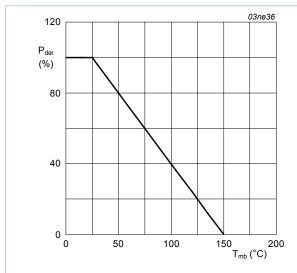
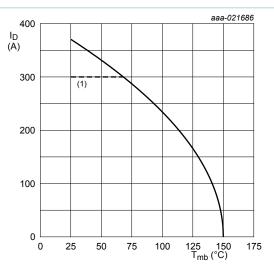


Fig. 1. Normalized total power dissipation as a function of mounting base temperature

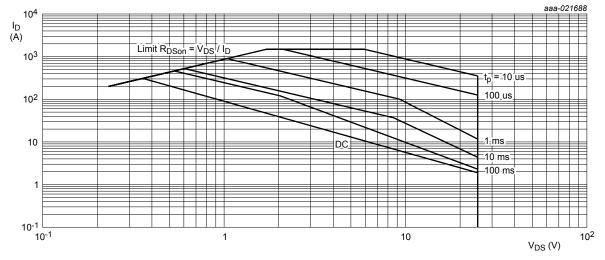
$$P_{der} = \frac{P(tot)}{P_{tot(25^{\circ}C)}} \times 100\%$$



 $V_{GS} \ge 10 \text{ V}$

(1) 300A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, Thermal design and operating temperature

Fig. 2. Continuous drain current as a function of mounting base temperature



T_{mb} = 25 °C; I_{DM} is a single pulse

Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4	-	0.59	0.79	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	Fig. 5 Fig. 6	-	50 125	-	K/W K/W

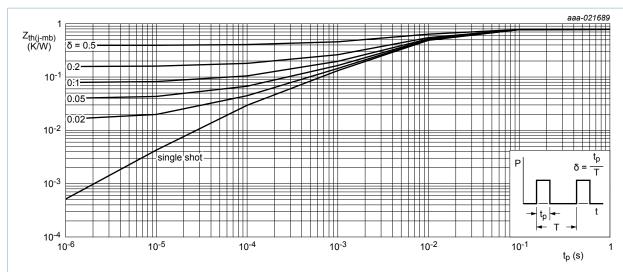


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

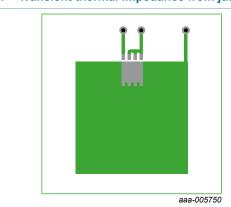


Fig. 5. PCB layout for thermal impedance junction to ambient 1" square pad; FR4 Board; 2oz copper

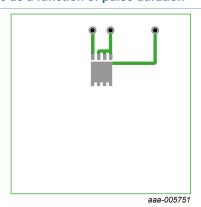


Fig. 6. PCB layout for thermal resistance junction to ambient minimum footprint; FR4 Board; 2oz copper

10. Characteristics

Table 7 Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		'			
V _{(BR)DSS}	drain-source	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	25	-	-	V
	breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 ^{\circ}C$	22.5	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.2	1.66	2.2	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-5.1	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μΑ
		V _{DS} = 20 V; V _{GS} = 0 V; T _j = 125 °C	-	68.5	-	μΑ
I _{GSS}	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 25 A; T _j = 25 °C; Fig. 10	-	0.76	0.92	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 150 °C; Fig. 10; Fig. 11	-	-	1.47	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10	-	0.57	0.72	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 150 °C; Fig. 10; Fig. 11	-	-	1.15	mΩ
R _G	gate resistance	f = 1 MHz	-	1.35	-	Ω
Dynamic ch	naracteristics					
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 10 V; Fig. 12; Fig. 13	-	110.2	-	nC
		I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13	-	50.9	-	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V	-	45.8	-	nC
Q_{GS}	gate-source charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V;	-	18.8	-	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 12; Fig. 13	-	11.9	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	6.9	-	nC
Q_{GD}	gate-drain charge		-	11.9	-	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 12 V; <u>Fig. 12</u> ; <u>Fig. 13</u>	-	2.6	-	V

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
C _{iss}	input capacitance	V _{DS} = 12 V; V _{GS} = 0 V; f = 1 MHz;		-	8320	-	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u>		-	2982	-	pF
C _{rss}	reverse transfer capacitance			-	522	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 12 V; R_L = 0.6 Ω ; V_{GS} = 4.5 V;		-	42.2	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$		-	48.3	-	ns
t _{d(off)}	turn-off delay time			-	53.1	-	ns
t _f	fall time			-	38.2	-	ns
Q _{oss}	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 12 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}$		-	54	-	nC
Source-dra	ain diode						
V _{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 15</u>		-	0.77	1.2	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$		-	57.7	-	ns
Qr	recovered charge	V _{DS} = 12 V; <u>Fig. 16</u>	[1]	-	83.2	-	nC
t _a	reverse recovery rise time			-	30.5	-	ns
t _b	reverse recovery fall time			-	27.2	-	ns
S	softness factor			-	0.9	-	

[1] includes capacitive recovery

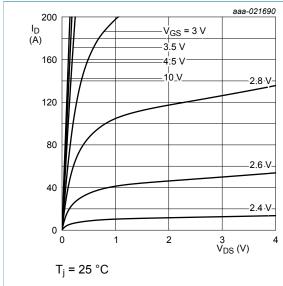


Fig. 7. Output characteristics; drain current as a function of drain-source voltage; typical values

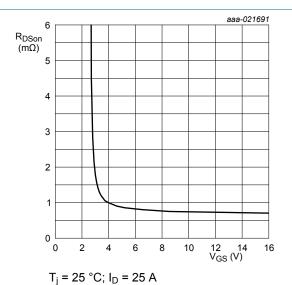


Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

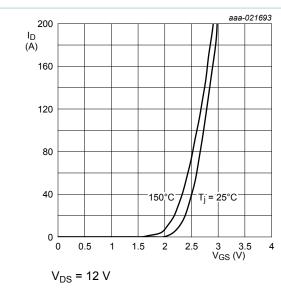


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

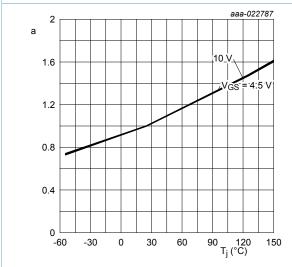


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$

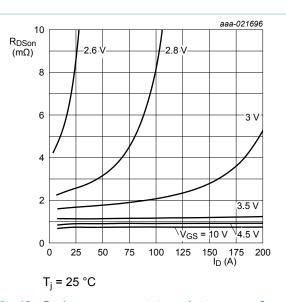


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

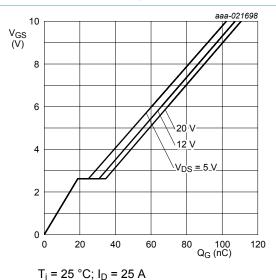


Fig. 12. Gate-source voltage as a function of gate charge; typical values

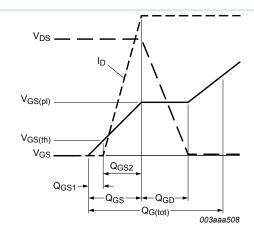
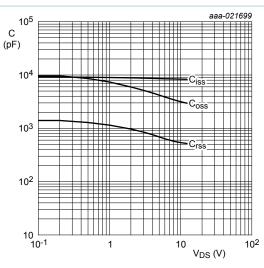


Fig. 13. Gate charge waveform definitions



 $V_{GS} = 0 V$; f = 1 MHz

Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

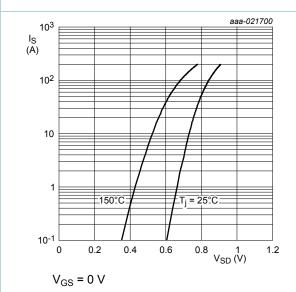


Fig. 15. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

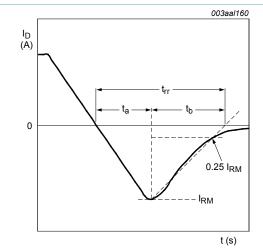
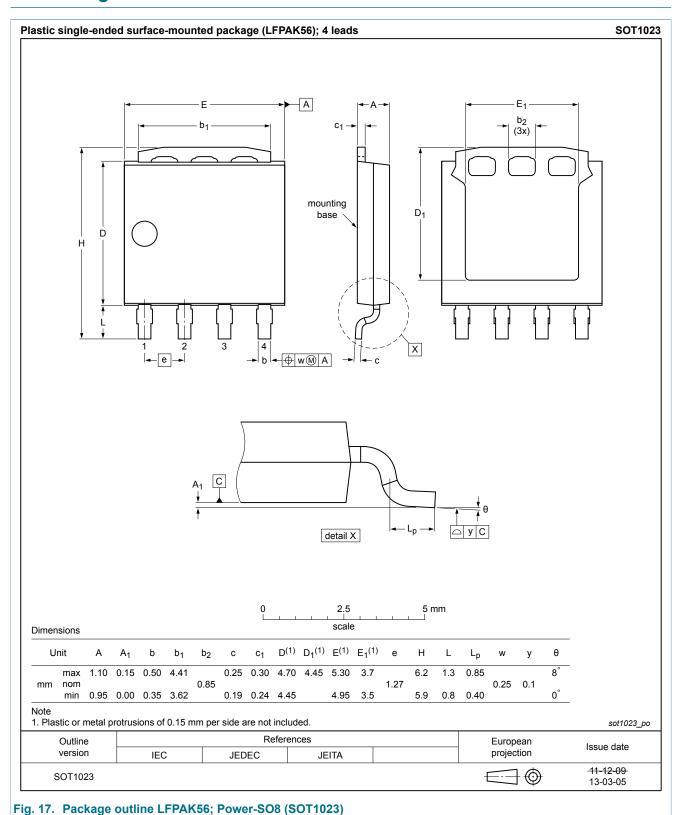


Fig. 16. Reverse recovery timing definition

11. Package outline



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Document status [1][2]	Product status [3]	Definition
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